

1. Features

- Typical 1dB bandwidth of 13.9 MHz
- High attenuation
- Single Ended Operation
- Dual In-line Package (DIP)

RoHS Compliant

Tested by SGS Testing Korea

2. Electrical Specifications

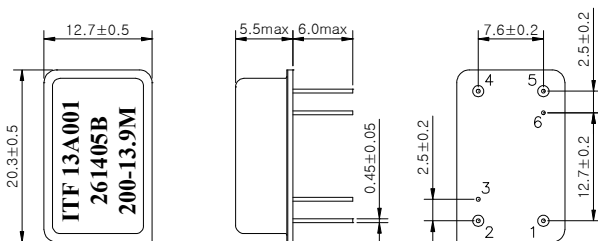
Source and Load Impedance = 50Ω

Room Temperature : +25°C

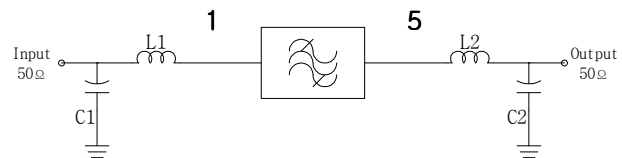
		Minimum	Typical	Maximum
Center Frequency (fo)	MHz	-	200.0	-
Insertion Loss	dB	-	29.5	31.0
1dB Bandwidth	MHz	13.80	13.95	-
3dB Bandwidth	MHz	-	14.25	-
45dB Bandwidth	MHz	-	15.60	15.75
Amplitude Ripple (Fo±6.7575MHz)	dB	-	0.65	1.2
Group Delay Variation (Fo±6.7575MHz)	nsec	-	35	100
Absolute Delay	usec	-	2.29	2.30
Ultimate Rejection	dB	47	53	-
Temperature Coefficient of Frequency	ppm/°C	-	-18	-
Substrate Material	-		112-LT	

Input Power : +10dBm

D2012 Package Dimension



Matching Schematic



L1 = 27nH, L2 = 22nH, C1 = C2=30pF

Dimensions shown are nominal in millimeters

Base : Fe(SPCC), Au plating over Ni plated
Cap : Cu & Cr Alloy, Ni Plated
Termination : Kovar, Au Plated

Pin Configuration

	1	Ground	2,4
Input	1	Ground	2,4
Output	5	Others	Ground

3. Typical Performance (at +25°C)

